INTEGRATED CIRCUITS

TYPES TLOGO, TLOGOA, TLOG1, TLOG1A, TLOG1B, TL062, TL062A, TL062B, TL064, TL064A, TL064B LOW-POWER JEET-INPUT OPERATIONAL AMPLIFIERS

BULLETIN NO. DL-S 12647, NOVEMBER 1978-REVISED OCTOBER 1979

19 DEVICES COVER COMMERCIAL, INDUSTRIAL, AND MILITARY **TEMPERATURE RANGES**

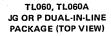
- Very Low Power Consumption
- Typical Supply Current . . . 200 μA
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- Output Short-Circuit Protection

- High Input Impedance . . . JFET-Input
- Internal Frequency Compensation
- Latch-Up-Free Operation
- High Slew Rate . . . 3.5 V/μs Typ

description

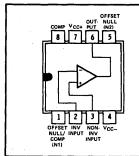
The JFET-input operational amplifiers of the TL061 series are designed as low-power versions of the TL081 series amplifiers. They feature high input impedance, wide bandwidth, high slew rate, and low input offset and bias currents. The TL061 series features the same terminal assignments as the TL071 and TL081 series. Each of these JFET-input operational amplifiers incorporates well-matched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit.

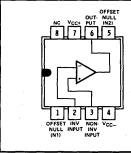
Device types with an "M" suffix are characterized for operation over the full military temperature range of -55°C to 125°C, those with an "I" suffix are characterized for operation from -25°C to 85°C, and those with a "C" suffix are characterized for operation from 0°C to 70°C.

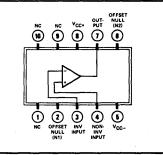


TL061, TL061A, TL061B JG OR P DUAL-IN-LINE PACKAGE (TOP VIEW)

TL061 **U FLAT PACKAGE** (TOP VIEW)



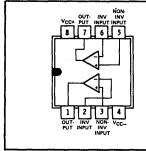


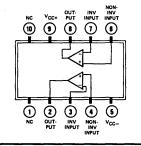


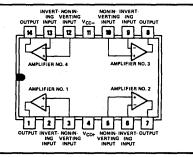
TL062, TL062A, TL062B JG OR P DUAL-IN-LINE PACKAGE (TOP VIEW)

TL062 U FLAT PACKAGE (TOP VIEW)

TL064...J, N, OR W PACKAGE TL064A, TL064B...J OR N PACKAGE (TOP VIEW)



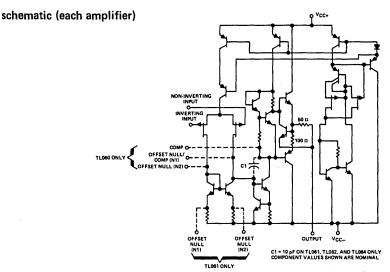




NC-No internal connection

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TYPES TLOGO, TLOGOA, TLOG1, TLOG1A, TLOG1B, TLOG2, TLOG2A, TLOG2B, TLOG4, TLOG4A, TLOG4B LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS



absolute maximum ratings over operating free-air temperature range (unless other wise noted)

	TL06_M	TL06I	TL06_C TL06_AC TL06_BC	UNIT	
Supply voltage, V _{CC+} (see Note 1)					
	-18	-18	-18	V	
Differential input voltage (see Note 2)					
Input voltage (see Notes 1 and 3)					
Duration of output short circuit (see Note 4)					
ontinuous total dissipation at (or below) J, JG, N, P, or W package				mW	
25° C free-air temperature (see Note 5) U package					
Operating free-air temperature range					
Storage temperature range					
_ead temperature 1/16 inch (1,6 mm) from case for 60 seconds				°c	
Lead temperature 1/16 inch (1,6 mm) from case for 10 seconds N or P package					
	U package J, JG, U, or W package	18 -18 ±30 ±15 Unlimited J, JG, N, P, or W package 680 U package 675 -55 to 125 -65 to 150 J, JG, U, or W package 300	18 18 -18 -18 +30 ±30 ±30 ±15 ±15 Unlimited Unlimited Unlimited Upackage 680 680 680 680 680 680 655 -55 to 125 -25 to 85 -65 to 150 -65 to 150 J, JG, U, or W package 300 300	TL06_M TL06_I TL06_BC 18 18 18 18 -18 -18 -18 -18 -18 -18 -1	

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 - 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal,
 - 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
 - 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
 - For operation above 25°C, free-air temperature, refer to Dissipation Derating Table. In the J and JG packages, TL06_M chips are alloy-mounted; TL06_I, TL06_C, TL06_AC, and TL06_BC chips are glass-mounted.

DISSIPATION DERATING TABLE

DAGKAGE	POWER	DERATING	ABOVE
PACKAGE	RATING	FACTOR	TA
J (Alloy-Mounted Chip)	680 mW	11.0 mW/°C	88°C
J (Glass-Mounted Chip)	680 mW	8.2 mW/°C	67°C
JG (Alloy-Mounted Chip)	680 mW	8.4 mW/°C	69°C
JG (Glass-Mounted Chip)	680 mW	6.6 mW/°C	47°C
N	680 mW	9.2 mW/°C	76°C
P	680 mW	8.0 mW/°C	65°C
U	675 mW	5.4 mW/°C	25° C
w	680 mW	8.0 mW/°C	65° C

DEVICE TYPES, SUFFIX VERSIONS, AND PACKAGES

	TL060	TL061	TL062	TL064
TL06_M	JG	JG, U	JG, U	J, W
TL06_1	JG, P	JG, P	JG, P	J, N
TL06_C	JG, P	JG, P	JG, P	J, N
TL06_AC	JG, P	JG, P	JG, P	J, N
TL06_BC		JG, P	JG, P	J, N

TYPES TLO60, TLO60A, TLO61, TLO61A, TLO61B, TL062, TL062A, TL062B, TL064, TL064A, TL064B LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS

electrical characteristics, VCC+ = ±15 V													
PARAMETER TEST CONDITIONS [†]				TL06_M		м	TL06_I			TL06_C TL06_AC			UNIT
	TANAMETEN	TEST CONDITIONS.							TL06_BC				
				MIN		MAX	MIN		MAX	MIN	TYP		
		['60, '61, '62		3	6		3	6		3	15	4
		$R_S = 50 \Omega$,	'64	ļ	3	9		3	6		3	15	4
		T _A = 25°C	'60A, '61A, '62A, '64A				ļ				3	6	1
۷ıo	Input offset voltage		'61B, '62B, '64B								2	3	im∨ l
	,	ĺ	′60, ′61, ′62			9			9			20	
		$R_S = 50 \Omega$,	′64			15			9			20	
		T _A = full range	'60A, '61A, '62A, '64A									7.5	1
			'61B, '62B, '64B									5	ļ
αVIO	Temperature coefficient of input offset voltage	$R_S = 50 \Omega$,	T _A = full range		10			10			10		μV/°C
			'60, '61, '62, '64		5	100		5	100		5	200	Ì
		T _A = 25°C	'60A, '61A, '62A, '64A								5	100	pΑ
110	Input offset current‡		'61B, '62B, '64B								5	100	
10			'60, '61, '62, '64			20	L		10			5	nA
		T _A = full range	'60A, '61A, '62A, '64A									3	
			'61B, '62B, '64B									3	
	Input bias current‡		'60, '61, '62, '64		30	200		30	200		30	400	
:		T _A = 25°C	'60A, '61A, '62A, '64A							<u> </u>	30	200	pΑ
Iв			'61B, '62B, '64B							ļ	30	200	
		T _A = full range	'60, '61, '62, '64			50			20			10	-
			'60A, '61A, '62A, '64A							ļ		7	nA
			'61B, '62B, '64B									7	-
V	Common-mode input	T 05°0	'60, '61, '62, '64	±11	±12		±11.	5 ±12		±10	±11		١
VICR	voltage range	T _A = 25°C	'60A, '61A, '62A, '64A								±12		\
	A4	T - 25°C	'61B, '62B, '64B	20	27		20			±11.5			ļ
VOPP	Maximum peak-to-peak output voltage swing	T _A = 25°C,	$R_L = 10 \text{ k}\Omega$	20			20	27		20	27		V
	output vortage swing	$T_A = \text{full range},$ $R_1 \ge 10 \text{ k}\Omega,$	'60, '61, '62, '64	4	6		4	6		3	6		-
}		$V_0 = \pm 10 \text{ V}$	'60A, '61A, '62A, '64A	-4			-	- 0		4	6		
	Large-signal differential	$T_A = 25^{\circ}C$	'61B, '62B, '64B							4	6		{
AVD	voltage amplification	$R_L \ge 10 \text{ k}\Omega$	'60, '61, '62, '64	4			4			3			V/mV
	vortage amplification	$V_0 = \pm 10 \text{ V},$	'60A, '61A, '62A, '64A	-			-			4			1
		T _A = full range	'61B, '62B, '64B						_	4			1
B ₁	Unity-gain bandwidth	$T_A = 1011 \text{ Tallige}$ $T_A = 25^{\circ}\text{C}$,	R _L = 10 kΩ	-	1			1		-	1		MHz
rj	Input resistance	T _A = 25°C	10 Kaz		1012		 	1012			1012		Ω
-1			'60, '61, '62, '64	80	86		80	86		70	76		34
CMRR	Common-mode rejection	_	'60A, '61A, '62A, '64A	55			- 50			80	86		dB
	ratio	T _A = 25°C	'61B, '62B, '64B				 			80	86		"B
ksvr			'60, '61, '62, '64	80	95		80	95		70	95		
			'60A, '61A, '62A, '64A	- 30			- 50	30		80	95		dB
0111			'61B, '62B, '64B	 						80	95		""
		No load,	No signal,						~	- 50			
PD:	(each amplifier)	T _A = 25°C	g		6	7.5	}	6	7.5		6	7.5	mW
	Supply current	No load,	No signal,										
Icc	(each amplifier)	T _A = 25°C	3,	[200	250		200	250	1	200	250	μA
V ₀₁ /V ₀₂	Channel separation	A _{VD} = 100,	T _A = 25°C		120			120	-		120		dB
													

[†]All characteristics are specified under open-loop conditions unless otherwise noted. Full range for T_A is -55°C to 125°C for TL06_M; -25°C to 85°C for TL06_I; and 0°C to 70°C for TL06_C, TL06_AC, and TL06_BC.

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[‡]Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as is possible.

TYPES TL060, TL060A, TL061, TL061A, TL061B, TL062, TL062A, TL062B, TL064, TL064A, TL064B LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS

operating characteristics, V_{CC±} = ±15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TL06_M			ALL OTHERS			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	ONII
SR	Slew rate at unity gain	V _I = 10 V, C _L = 100 pF,	R _L = 10 kΩ, See Figure 1	2	3.5			3.5		V/μs
tr	Rise time	V _I = 20 mV,	R _L = 10 kΩ,		0.2			0.2		μς
	Overshoot factor	CL = 100 pF,	See Figure 1		10%			10%		
٧n	Equivalent input noise voltage	R _S = 100 Ω,	f = 1 kHz		42			42		nV/√Hz

PARAMETER MEASUREMENT INFORMATION

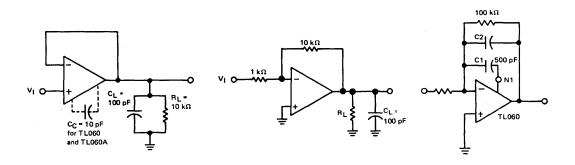
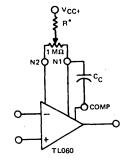


FIGURE 1-UNITY-GAIN AMPLIFIER

FIGURE 2-GAIN-OF-10 INVERTING AMPLIFIER FIGURE 3-FEED-FORWARD COMPENSATION

INPUT OFFSET VOLTAGE NULL CIRCUITS



*For best results use R = 20 M Ω for $V_{CC\pm}$ = ±15 V to R = 5 M Ω for $V_{CC\pm}$ = ±3 V.

FIGURE 4

FIGURE 5

TL061

vcc-

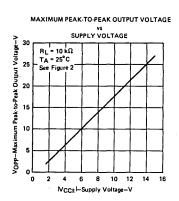
TEXAS INSTRUMENTS

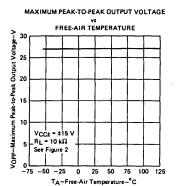
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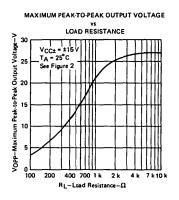
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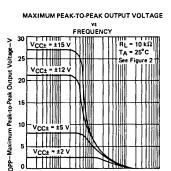
TYPES TLOGO, TLOGOA, TLOG1, TLOG1A, TLOG1B, TLOG2, TLOG2A, TLOG2B, TLOG4, TLOG4A, TLOG4B LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS

TYPICAL CHARACTERISTICS[†]



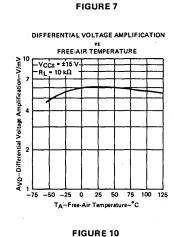






f-Frequency-Hz

FIGURE 6



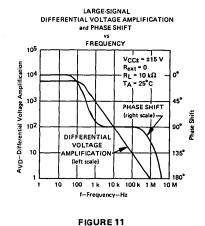
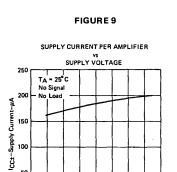
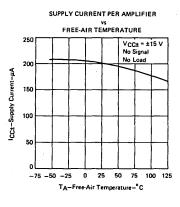


FIGURE 8





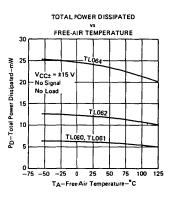


FIGURE 12

VCC±1-Supply Voltage-V

10

0 r

3

FIGURE 13

FIGURE 14

†Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. A 10-pF compensation capacitor is used with TL060 and TL060A.

TYPES TL060, TL060A, TL061, TL061A, TL061B, TL062, TL062A, TL062B, TL064, TL064A, TL064B LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS

R_L = 10 kΩ

CL = 100 pF

= 25°C

t-Time-us

8

-6

120



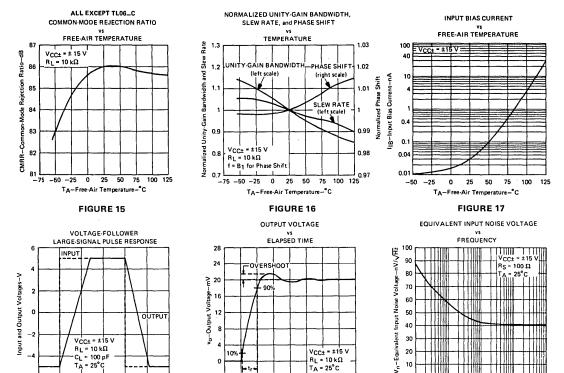


FIGURE 20 FIGURE 18 FIGURE 19 †Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices, A 10-pF compensation capacitor is used with TL060 and TL060A.

t-Time-µs

VCC± = ±15 V

RL = 10 kΩ

TA = 25°C

20

10

10 40 100 400 1 k

f-Frequency-Hz

4 k 10 k

40 k 100 k

TYPICAL APPLICATION DATA

109

0 0.2 0.4 0.6 0.8 1 1.2 14

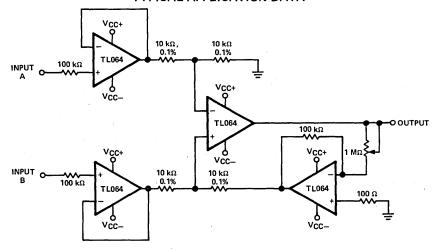


FIGURE 21-INSTRUMENTATION AMPLIFIER